



## High-Speed Quad SPST CMOS Analog Switch

### FEATURES

- Fast Switching— $t_{ON}$ : 38 ns
- Low On-Resistance: 25  $\Omega$
- Low Leakage: 100 pA
- Low Charge Injection
- TTL/CMOS Logic Compatible
- Single Supply Compatibility
- High Current Rating: -30 mA

### BENEFITS

- Faster Throughput
- Higher Accuracy
- Reduced Pedestal Error
- Upgrades Existing Designs
- Simple Interfacing
- Replaces HI201HS, ADG201HS
- Space Savings (TSSOP)

### APPLICATIONS

- Data Acquisition
- Hi-Rel Systems
- Sample-and-Hold Circuits
- Communication Systems
- Automatic Test Equipment
- Integrator Reset Circuits
- Choppers
- Gain Switching
- Avionics

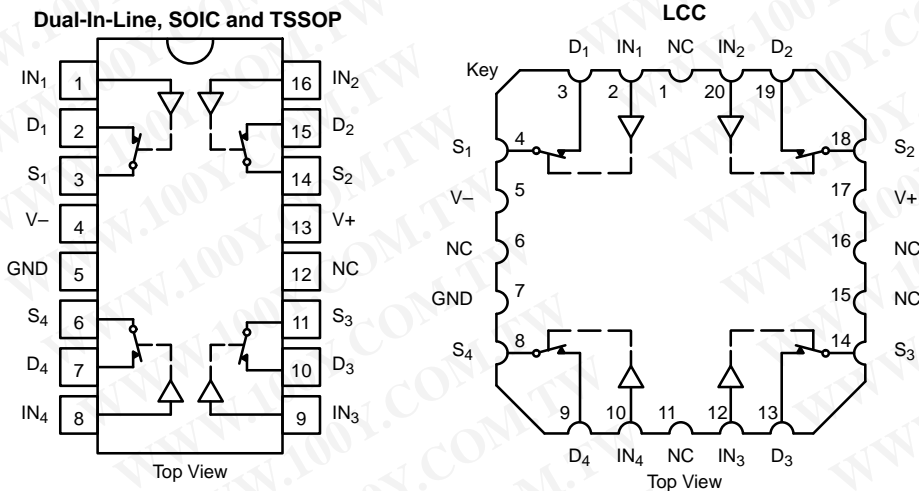
### DESCRIPTION

The DG201HS is an improved monolithic device containing four independent analog switches. It is designed to provide high speed, low error switching of analog signals. Combining low on-resistance (25  $\Omega$ ) with high speed ( $t_{ON}$ : 38 ns), the DG201HS is ideally suited for high speed data acquisition requirements.

To achieve high voltage ratings and superior switching performance, the DG201HS is built on a proprietary high-voltage silicon-gate process. An epitaxial layer prevents latchup.

Each switch conducts equally well in both directions when on, and blocks input voltages to the supply values, when off.

### FUNCTIONAL BLOCK DIAGRAM AND PIN CONFIGURATION



TRUTH TABLE	
Logic	Switch
0	ON
1	OFF

Logic "0"  $\leq$  0.8 V  
 Logic "1"  $\geq$  2.4 V

ORDERING INFORMATION		
Temp Range	Package	Part Number
-40 to 85°C	16-Pin Plastic DIP	DG201HSDJ
	16-Pin Narrow SOIC	DG201HSDY
	16-Pin TSSOP	DG201HSDQ
-55 to 125°C	16-Pin CerDIP	DG201HSAK/883
	LCC-20	DG201HSAZ/883

**ABSOLUTE MAXIMUM RATINGS**

V+ to V- ..... 44 V  
 GND to V- ..... 25 V  
 Digital Inputs<sup>a</sup> V<sub>S</sub>, V<sub>D</sub> ..... (V-) -4 V to (V+) +4 V  
 or 30 mA, whichever occurs first  
 Continuous Current (Any Terminal) ..... 30 mA  
 Current, S or D (Pulsed 1 ms, 10% duty cycle) ..... 100 mA  
 Storage Temperature (A Suffix) ..... -65 to 150°C  
 (D Suffix) ..... -65 to 125°C  
 Power Dissipation (Package)<sup>b</sup>  
 16-Pin Plastic DIP<sup>c</sup> ..... 470 mW

16-Pin CerDIP<sup>d</sup> ..... 900 mW  
 16-Pin Narrow Body SOIC and TSSOP<sup>e</sup> ..... 600 mW  
 LCC-20<sup>d</sup> ..... 900 mW

Notes:

- a. Signals on S<sub>X</sub>, D<sub>X</sub>, or IN<sub>X</sub> exceeding V+ or V- will be clamped by internal diodes. Limit forward diode current to maximum current ratings.
- b. All leads welded or soldered to PC board.
- c. Derate 6 mW/°C above 75°C.
- d. Derate 12 mW/°C above 75°C.
- e. Derate 7.6 mW/°C above 75°C.

**SCHEMATIC DIAGRAM (TYPICAL CHANNEL)**

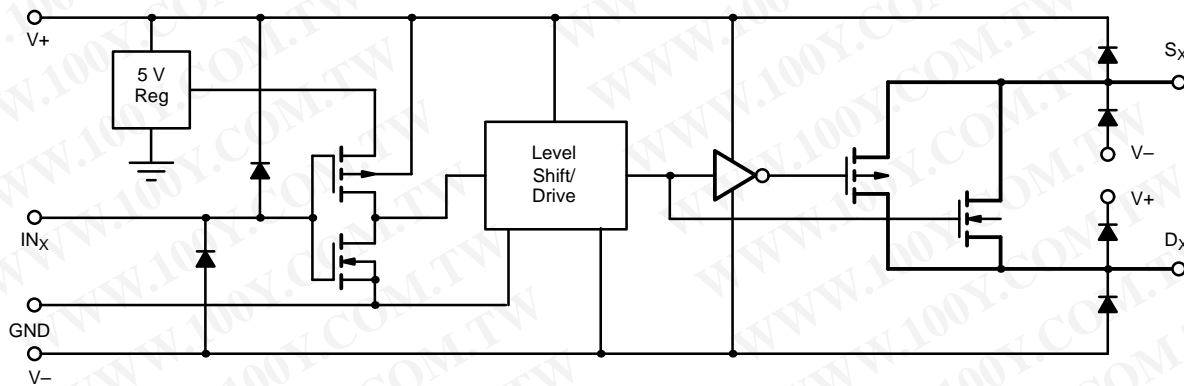


FIGURE 1.



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**DG201HS**  
**Vishay Siliconix**

SPECIFICATIONS <sup>a</sup>									
Parameter	Symbol	Test Conditions Unless Specified $V_+ = 15\text{ V}, V_- = -15\text{ V}$ $V_{IN} = 3\text{ V}, 0.8\text{ V}^f$	Temp <sup>b</sup>	Typ <sup>c</sup>	A Suffix -55 to 125°C		D Suffix -40 to 85°C		Unit
					Min <sup>d</sup>	Max <sup>d</sup>	Min <sup>d</sup>	Max <sup>d</sup>	
<b>Analog Switch</b>									
Analog Signal Range <sup>e</sup>	$V_{ANALOG}$		Full		V-	V+	V-	V+	V
Drain-Source On-Resistance	$r_{DS(on)}$	$I_S = -10\text{ mA}, V_D = \pm 8.5\text{ V}$ $V_+ = 13.5\text{ V}, V_- = -13.5\text{ V}$	Room Full	25		50 75		50 75	$\Omega$
$r_{DS(on)}$ Match			Room	3					%
Switch Off Leakage Current	$I_{S(off)}$	$V_+ = 16.5\text{ V}, V_- = -16.5\text{ V}$ $V_D = \pm 15.5\text{ V}$ $V_S = \mp 15.5\text{ V}$	Room Full	0.1	-1 -60	1 60	-1 -20	1 20	nA
	$I_{D(off)}$		Room Full	0.1	-1 -60	1 60	-1 -20	1 20	
Channel On Leakage Current	$I_{D(on)}$	$V_+ = 16.5\text{ V}, V_- = -16.5\text{ V}$ $V_S = V_D = \mp 15.5\text{ V}$	Room Full	0.1	-1 -60	1 60	-1 -20	1 20	
<b>Digital Control</b>									
Input, High Voltage	$V_{INH}$		Full		2.4		2.4		V
Input, Low Voltage	$V_{INL}$		Full			0.8		0.8	
Input Capacitance	$C_{in}$		Full	5					pF
Input Current	$I_{INL}$ or $I_{INH}$	$V_{IN}$ under test = 0.8 V, 3 V	Full		-1	1	-1	1	$\mu\text{A}$
<b>Dynamic Characteristics</b>									
Turn-On Time	$t_{ON}$	$R_L = 1\text{ k}\Omega, C_L = 35\text{ pF}$ $V_S = \pm 10\text{ V}, V_{INH} = 3\text{ V}$ See Figure 2	Room Full	48		60 75		60 75	ns
Turn-Off Time	$t_{OFF1}$		Room Full	30		50 70		50 70	
	$t_{OFF2}$		Room	150					
Output Settling Time to 0.1%	$t_s$		Room	180					
Charge Injection	Q	$C_L = 1\text{ nF}, V_S = 0\text{ V}$ $V_{gen} = 0\text{ V}, R_{gen} = 0\text{ }\Omega$	Room	-5					pC
OFF Isolation	OIRR	$R_L = 1\text{ k}\Omega, C_L = 10\text{ pF}$ $f = 100\text{ kHz}$	Room	85					dB
Crosstalk (Channel-to-Channel)	$X_{TALK}$	Any Other Channel Switches $R_L = 1\text{ k}\Omega, C_L = 10\text{ pF}$ $f = 100\text{ kHz}$	Room	100					
Source Off Capacitance	$C_{S(off)}$	$V_S, V_D = 0\text{ V}, f = 1\text{ MHz}$	Room	8					pF
Drain Off Capacitance	$C_{D(off)}$		Room	8					
Channel On Capacitance	$C_{D(on)}$		Room	30					
Drain-to-Source Capacitance	$C_{DS(off)}$		Room	0.5					
<b>Power Supplies</b>									
Positive Supply Current	$I_+$	$V_+ = 15\text{ V}, V_- = -15\text{ V}$ $V_{IN} = 0\text{ or }5\text{ V}$	Room Full	4.5		10		10	mA
Negative Supply Current	$I_-$		Room Full	3.5	-6		-6		
Power Consumption <sup>g</sup>	$P_C$		Full				240		240



SPECIFICATIONS <sup>a</sup> FOR SINGLE SUPPLY									
Parameter	Symbol	Test Conditions Unless Specified $V_+ = 10.8\text{ V to }16.5\text{ V}$ $V_- = \text{GND} = 0\text{ V}$ $V_{IN} = 3\text{ V, }0.8\text{ V}^f$	Temp <sup>b</sup>	Typ <sup>c</sup>	A Suffix -55 to 125°C		D Suffix -40 to 85°C		Unit
					Min <sup>d</sup>	Max <sup>d</sup>	Min <sup>d</sup>	Max <sup>d</sup>	
<b>Analog Switch</b>									
Analog Signal Range <sup>e</sup>	$V_{ANALOG}$		Full		0	$V_+$	0	$V_+$	V
Drain-Source On-Resistance	$r_{DS(on)}$	$I_S = -10\text{ mA, }V_D = 8.5\text{ V}$ $V_+ = 10.8\text{ V}$	Room Full	65		90 120		90 120	$\Omega$
Switch Off Leakage Current	$I_{S(off)}$	$V_+ = 16.5\text{ V, }V_S = 0.5\text{ V, }10\text{ V}$ $V_D = 10\text{ V, }0.5\text{ V}$	Room Full	0.1	-1 -60	1 60	-1 -20	1 20	nA
	$I_{D(off)}$		Room Full	0.1	-1 -60	1 60	-1 -20	1 20	
Channel On Leakage Current	$I_{D(on)} + I_{S(on)}$	$V_+ = 16.5\text{ V, }V_D = 0.5\text{ V, }10\text{ V}$	Room Full	0.1	-1 -60	1 60	-1 -20	1 20	
<b>Digital Control</b>									
Input, High Voltage	$V_{INH}$		Full		2.4		2.4		V
Input, Low Voltage	$V_{INL}$		Full			0.8		0.8	
Input Capacitance	$C_{in}$		Full	5					pF
Input Current	$I_{INL}$ or $I_{INH}$	$V_+ = 16.5\text{ V}$ $V_{IN}$ under test = 0.8 V, 3 V	Full		-1	1	-1	1	$\mu\text{A}$
<b>Dynamic Characteristics</b>									
Turn-On Time	$t_{ON}$	$R_L = 1\text{ k}\Omega, C_L = 35\text{ pF, }V_S = 2\text{ V}$ $V = 10.8\text{ V, See Figure 2}$	Room Full			50 70		50 70	ns
Turn-Off Time	$t_{OFF1}$		Room Full			50 70		50 70	
	$t_{OFF2}$		Room	150					
Output Settling Time to 0.1%	$t_s$		Room	180					
Charge Injection	Q	$C_L = 1\text{ nF, }V_S = 0\text{ V}$ $V_{gen} = 0\text{ V, }R_{gen} = 0\text{ }\Omega$	Room	10					pC
Off Isolation	OIRR	$R_L = 1\text{ k}\Omega, C_L = 10\text{ pF}$ $f = 100\text{ kHz}$	Room	85					dB
Crosstalk (Channel-to-Channel)	$X_{TALK}$	Any Other Channel Switches $R_L = 1\text{ k}\Omega, C_L = 10\text{ pF}$ $f = 100\text{ kHz}$	Room	100					
Source Off Capacitance	$C_{S(off)}$	$f = 1\text{ MHz}$	Room	10					pF
Drain Off Capacitance	$C_{D(off)}$		Room	10					
Channel On Capacitance	$C_{D(on)}$		$V_{ANALOG} = 0\text{ V}$	Room	30				
<b>Power Supplies</b>									
Positive Supply Current	$I_+$	$V_+ = 15\text{ V, }V_{IN} = 0\text{ or }5\text{ V}$	Full			10		10	mA
Power Consumption <sup>c</sup>	$P_C$		Full			150		150	mW

Notes:

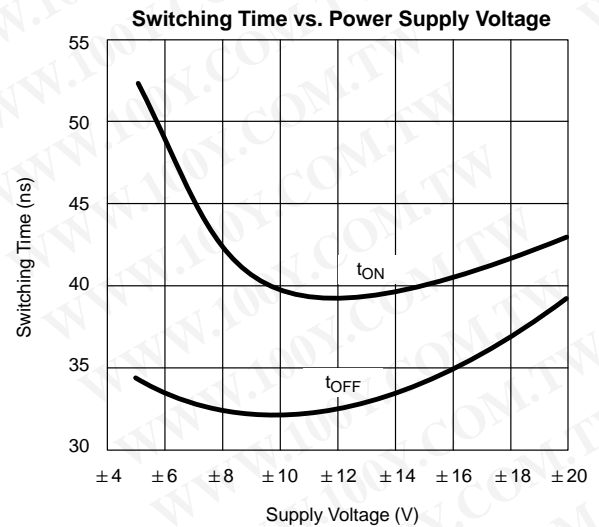
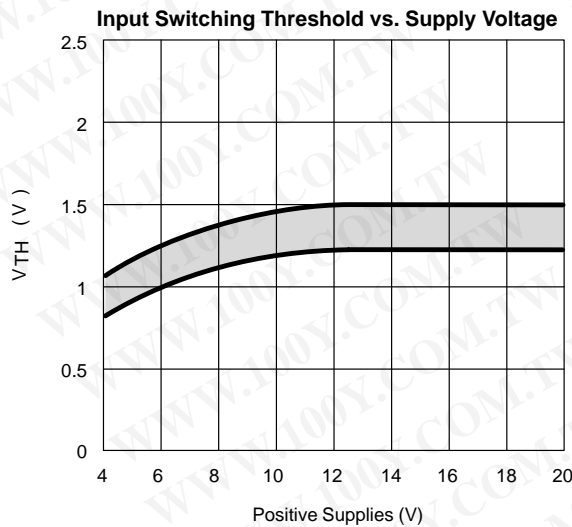
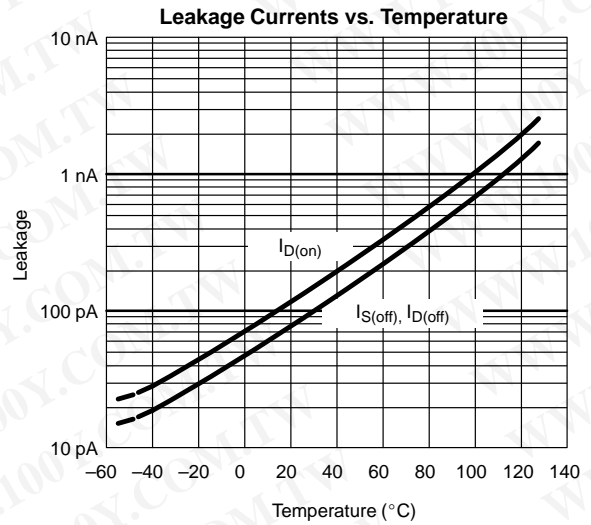
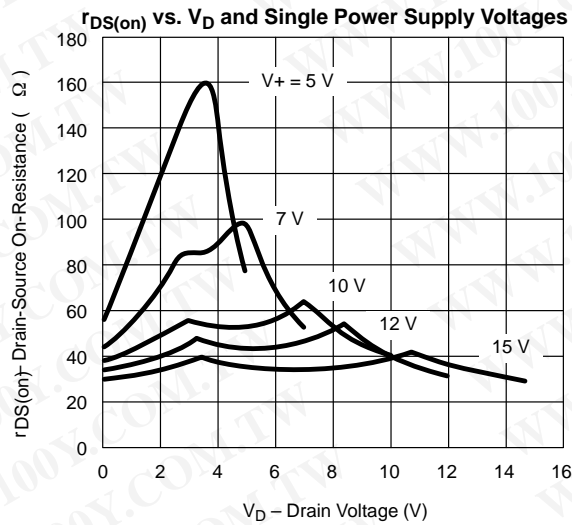
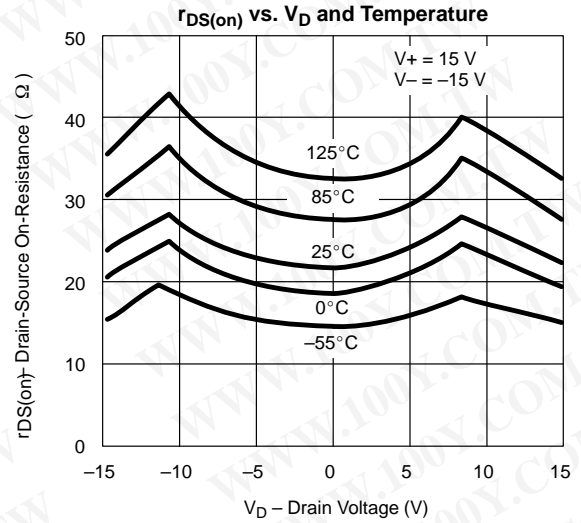
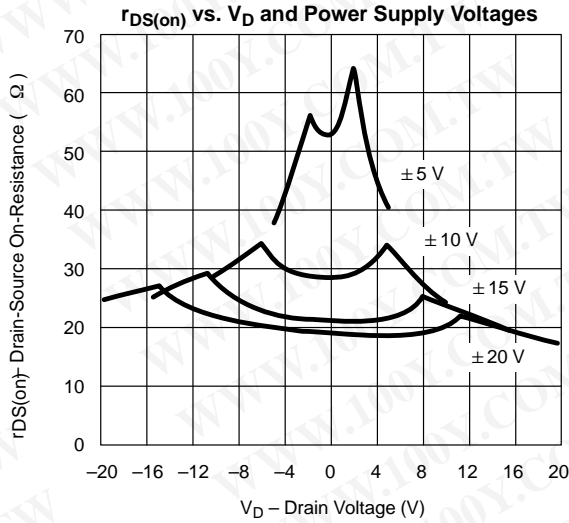
- Refer to PROCESS OPTION FLOWCHART.
- Room = 25°C, Full = as determined by the operating temperature suffix.
- Typical values are for DESIGN AID ONLY, not guaranteed nor subject to production testing.
- The algebraic convention whereby the most negative value is a minimum and the most positive a maximum, is used in this data sheet.
- Guaranteed by design, not subject to production test.
- $V_{IN}$  = input voltage to perform proper function.



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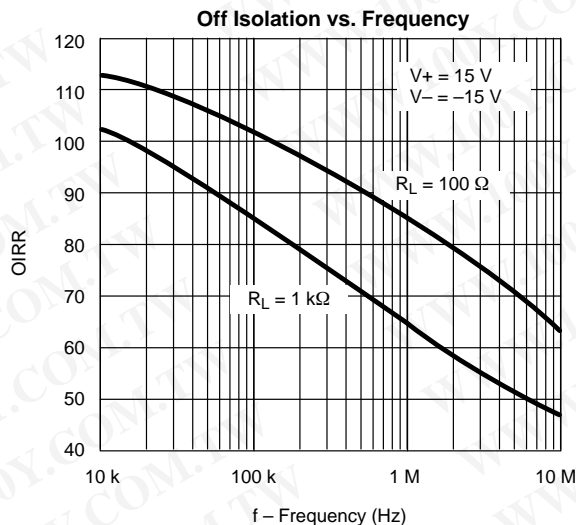
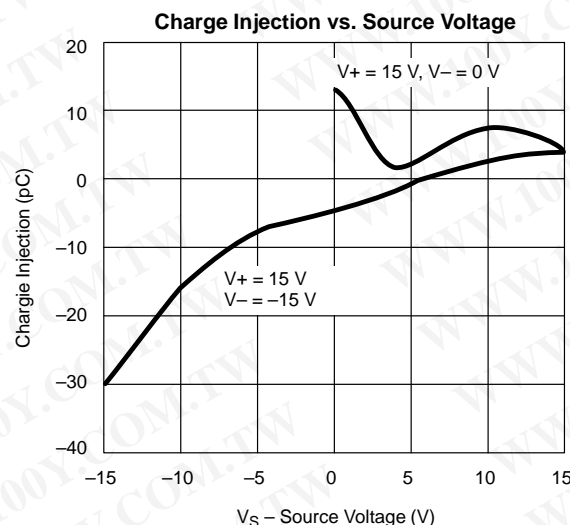
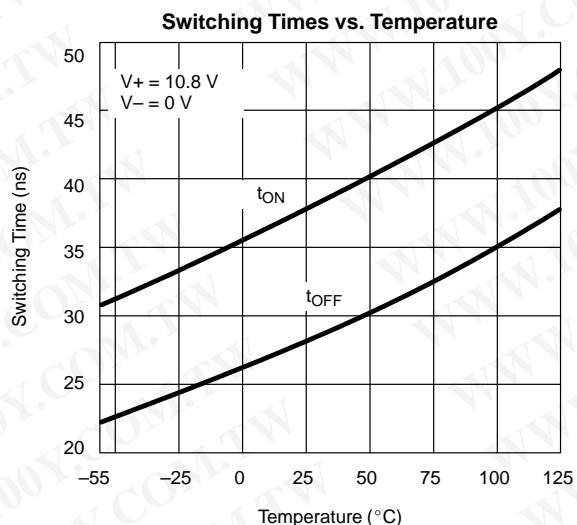
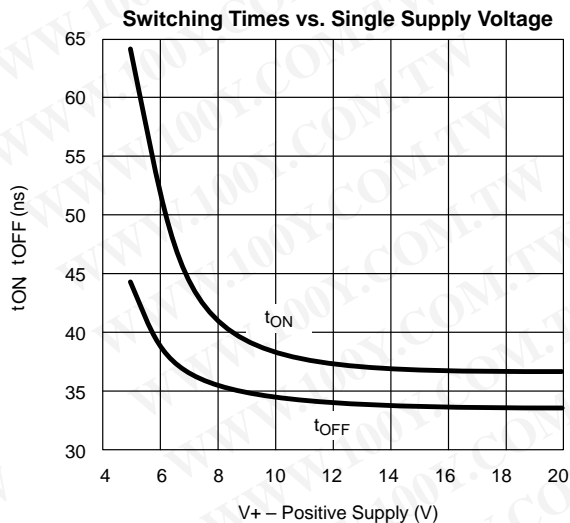
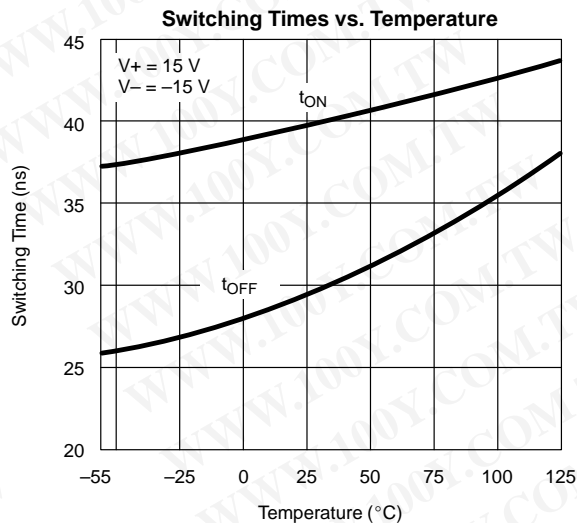
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**TYPICAL CHARACTERISTICS (25°C UNLESS NOTED)**

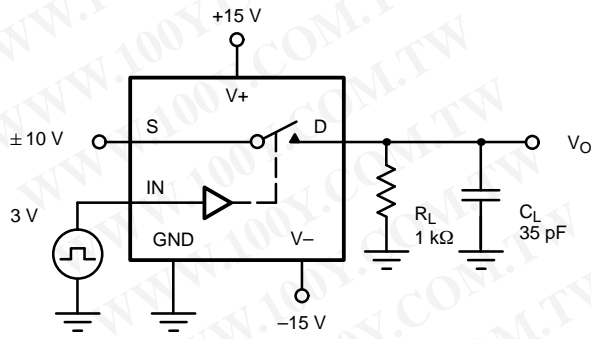




**TYPICAL CHARACTERISTICS (25°C UNLESS NOTED)**



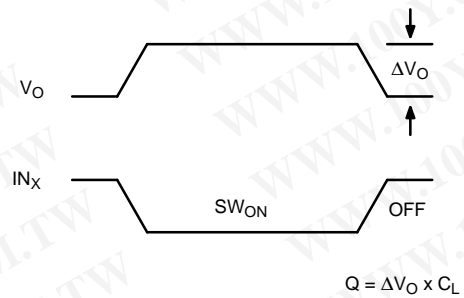
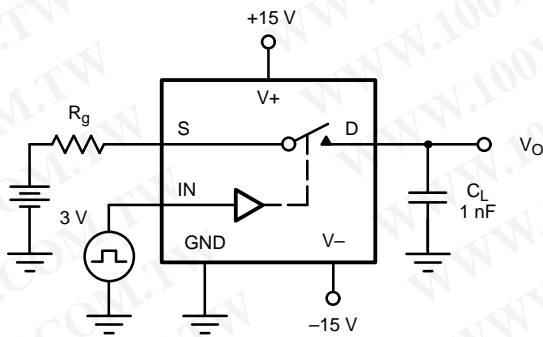
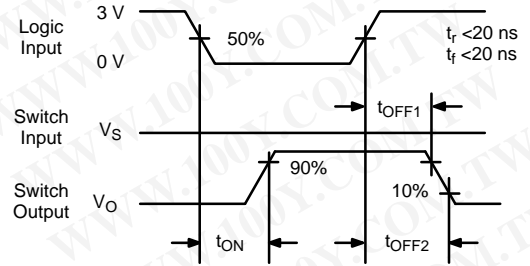
**TEST CIRCUITS**



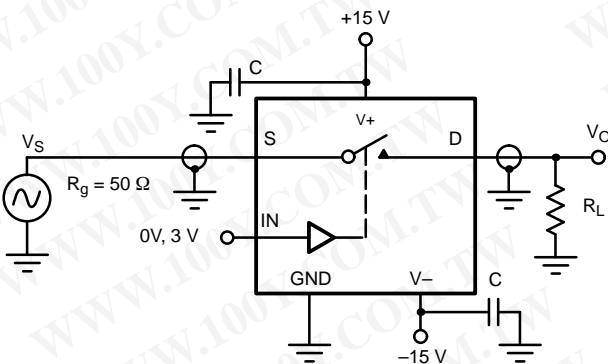
$C_L$  (includes fixture and stray capacitance)

$$V_O = V_S \frac{R_L}{R_L + \tau_{DS(on)}}$$

**FIGURE 2. Switching Time**

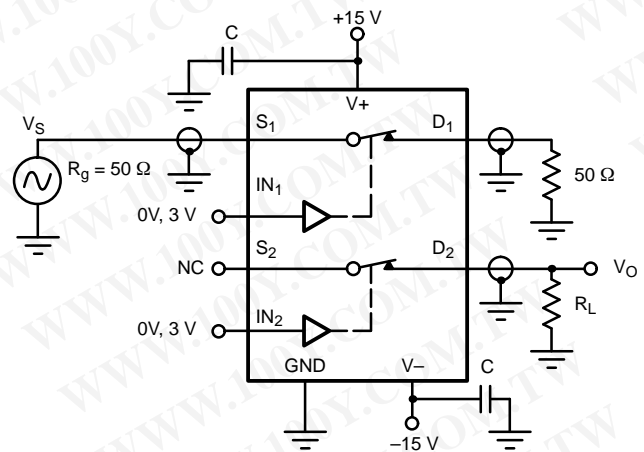


**FIGURE 3. Charge Injection**



$$\text{Off Isolation} = 20 \log \left| \frac{V_S}{V_O} \right|$$

**FIGURE 4. Off Isolation**



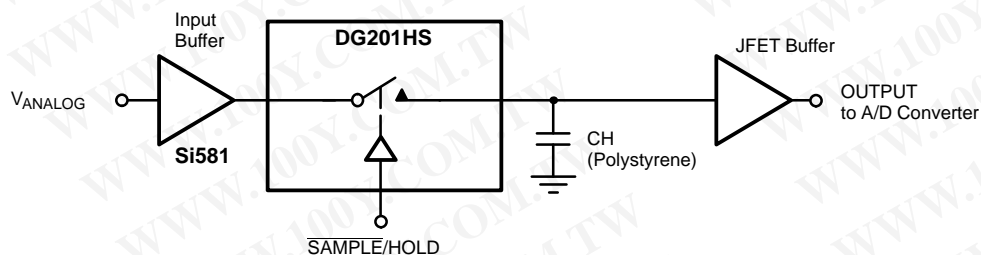
$$X_{TALK} \text{ Isolation} = 20 \log \left| \frac{V_S}{V_O} \right|$$

$C = \text{RF bypass}$

**FIGURE 5. Crosstalk**

### APPLICATIONS

A high-speed, low-glitch analog switch such as Vishay Siliconix's DG201HS improves the accuracy and shortens the acquisition and settling times of a sample-and-hold circuit.



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